MPX5050

Integrated silicon pressure sensor, on-chip signal conditioned, temperature compensated and calibrated

Rev. 12 — 9 June 2023

Product data sheet

1 General description

The MPXx5050 series piezoresistive transducer is a state-of-the-art monolithic silicon pressure sensor designed for a wide range of applications, but particularly those employing a microcontroller or microprocessor with A/D inputs. This patented, single element transducer combines advanced micromachining techniques, thin-film metallization, and bipolar processing to provide an accurate, high level analog output signal that is proportional to the applied pressure.

2 Feature and benefits

- 2.5 % Maximum Error over 0 ° to 85 °C
- · Ideally suited for Microprocessor or Microcontroller-based systems
- Temperature compensated over -40 ° to +125 °C
- · Patented silicon shear stress strain gauge
- · Durable epoxy unibody element
- Easy-to-use chip carrier option

3 Ordering information

Table 1. Ordering information

Type number	Package							
	Name	Description	Version					
MPX5050DP	SENSOR4F	Pressure sensor, 5 V, 0/50 kPa, Port; Unibody package, 4 terminals; 2.54 mm pitch; 17.78 mm x 29.48 mm x 10.67 mm body	SOT1756-1					
MPXV5050DP	SENSOR6F	Pressure sensor, 5 V, 0/50 kPa, Port, SO8, plastic, small outline package; 8 terminals; 2.54 mm pitch; 12.06 mm x 12.06 mm x 7.62 mm body	SOT1693-1					
MPXV5050GP	SO8	Pressure sensor, 5 V, 0/50 kPa, Port, 8 terminals; 2.54 mm pitch; 12.06 mm x 12.06 mm x 3.38 mm body body	SOT1693-3					
MPXV5050GC6T1	SO8	Pressure sensor, 5 V, 0/540 kPa, small outline package, Port, 8 terminals; 2.54 mm pitch; 10.67 mm x 10.67 mm x 12.96 mm body	SOT18454-1					



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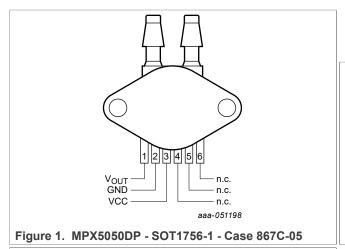
3.1 Ordering options

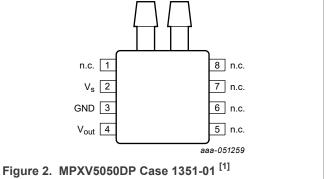
Table 2. Ordering options

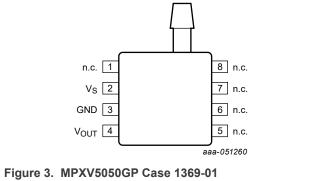
idolo 2. Gradinig optiono										
ORDERING INFORMATION										
Device Name	Case		# of Ports	i	F	Device				
	No.	None	Single	Dual	Gauge	Differential	Absolute	Marking		
Unibody Package (MPX5050 Series)										
MPX5050DP	867C			•		•		MPX5050DP		
Small Outline Packa	age (MPX)	/5050 Ser	ies)							
MPXV5050GP	1369		•		•			MPXV5050GP		
MPXV5050DP	1351			•		•		MPXV5050DP		
MPXV5050GC6T1	482A		•		•			MPXV5050G		

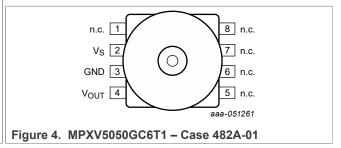
4 Pinning information

4.1 Pinning









^[1] Refer to Table 4 and style 2 in Figure 13 in Section 7 "Package outline"

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4.2 Pin description

Table 3. Pin descriptions - MPX5050DP

Symbol	Pin	Description
V _{OUT}	1	V _{OUT}
Ground	2	Ground
V _{CC}	3	Supply voltage
N.C.	4	No connection.
N.C.	5	No connection.
N.C.	6	No connection.

Table 4. Pin descriptions - MPXV5050GC6T1, MPXV5050DP, and MPXV5050GP

Symbol	Pin	Description
N.C.	1	No connect
Vs	2	Supply voltage
Ground	3	Ground
V _{OUT}	4	V _{OUT}
N.C.	5	No connect
N.C.	6	No connect
N.C.	7	No connect
N.C.	8	No connect

5 Limiting values

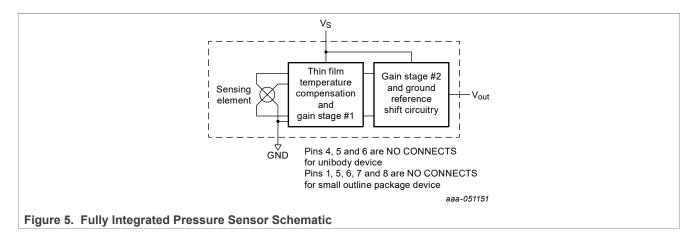
Table 5. Limiting values [1]

Rating	Symbol	Value	Unit
Maximum pressure (P1 > P2)	P _{max}	200	kPa
Storage temperature	T _{stg}	-40 to +125	°C
Operating temperature	T _A	-40 to +125	°C

^[1] Exposure beyond the specified limits may cause permanent damage or degradation to the device.

Figure 5 shows a block diagram of the internal circuitry integrated on a pressure sensor chip.

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6 Recommended operating conditions

Table 6. Recommended operating conditions

 $(V_S = 5.0 \text{ Vdc}, T_A = 25 ^{\circ}\text{C} \text{ unless otherwise noted, } P1 > P2. \text{ Decoupling circuit shown in } \underline{\text{Figure 8}} \text{ required to meet electrical specifications.)}$

Characteristic	Symbol	Min	Тур	Max	Unit
Pressure Range ^[1]	P _{OP}	0	_	50	kPa
Supply Voltage ^[2]	V _S	4.75	5.0	5.25	Vdc
Supply Current	Io	_	7.0	10	mAdc
Minimum Pressure Offset ^[3] (0 °C to 85 °C) @ V _S = 5.0 Volts	V _{off}	0.088	0.2	0.313	Vdc
Full Scale Output ^[4] (0 °C to 85 °C) @ V _S = 5.0 Volts	V _{FSO}	4.587	4.7	4.813	Vdc
Full Scale Span ^[5] (0 °C to 85 °C) @ V _S = 5.0 Volts	V _{FSS}	_	4.5	_	Vdc
Accuracy ^[6] (0 °C to 85 °C)	_	_	_	±2.5	%V _{FSS}
Sensitivity	V/P	_	90	_	mV/kPa
Response Time ^[7]	t _R	_	1.0	_	ms
Output Source Current at Full Scale Output	I _{o+}	_	0.1	_	mAdc
Warm-Up Time ^[8]	_	_	20	_	ms
Offset Stability ^[9]	_	_	± 0.5	_	%V _{FSS}

- [1] 1.0 kPa (kiloPascal) equals 0.145 psi.
- [2] Device is ratiometric within this specified excitation range.
- [3] Offset (V_{off}) is defined as the output voltage at the minimum rated pressure.
- [4] Full Scale Output (V_{FSO}) is defined as the output voltage at the maximum or full rated pressure.
- [5] Full Scale Span (V_{FSS}) is defined as the algebraic difference between the output voltage at full rated pressure and the output voltage at the minimum rated pressure.
- [6] Accuracy (error budget) consists of the following:
 - Linearity: Output deviation from a straight line relationship with pressure over the specified pressure range.

Temperature Hysteresis: Output deviation at any temperature within the operating temperature range, after the temperature is cycled to and from the minimum or maximum operating temperature points, with zero differential pressure applied.

Pressure Hysteresis: Output deviation at any pressure within the specified range, when this pressure is cycled to and from the minimum or maximum rated pressure at 25 °C.

TcSpan: Output deviation over the temperature range of 0 °C to 85 °C, relative to 25 °C.

 $TcOffset: Output \ deviation \ with \ minimum \ pressure \ applied, \ over \ the \ temperature \ range \ of \ 0\ ^{\circ}C, \ relative \ to \ 25\ ^{\circ}C.$

 $Variation\ from\ Nominal:\ The\ variation\ from\ nominal\ values,\ for\ Offset\ or\ Full\ Scale\ Span,\ as\ a\ percent\ of\ V_{FSS}\ at\ 25\ ^\circ C.$

MPX5050

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- [7] Response Time is defined as the time for the incremental change in the output to go from 10% to 90% of its final value when subjected to a specified step change in pressure.
- [8] Warm-up Time is defined as the time required for the product to meet the specified output voltage after the Pressure has been stabilized.
- [9] Offset Stability is the product's output deviation when subjected to 1000 hours of Pulsed Pressure, Temperature Cycling with Bias Test.

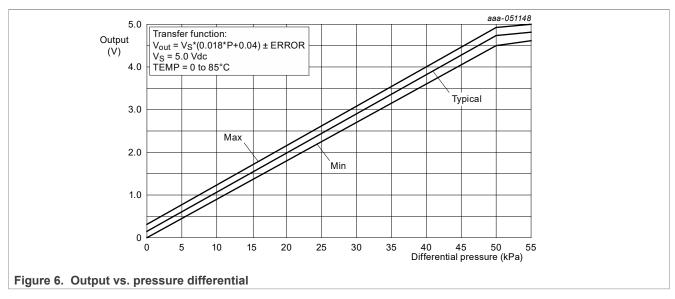
6.1 On-chip Temperature Compensation and Calibration

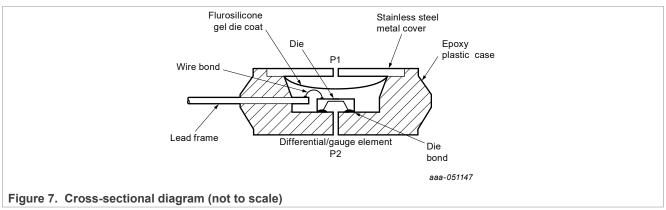
<u>Figure 7</u> illustrates the Differential/Gauge Sensing Chip in the basic chip carrier (Case 867). A fluorosilicone gel isolates the die surface and wire bonds from the environment, while allowing the pressure signal to be transmitted to the sensor diaphragm.

The MPX5050/MPXV5050G series pressure sensor operating characteristics, and internal reliability and qualification tests are based on use of dry air as the pressure media. Media, other than dry air, may have adverse effects on sensor performance and long-term reliability. Contact the factory for information regarding media compatibility in your application.

<u>Figure 6</u> shows the sensor output signal relative to pressure input. Typical, minimum, and maximum output curves are shown for operation over a temperature range of 0 °C to 85 °C using the decoupling circuit shown in <u>Figure 8</u>. The output will saturate outside of the specified pressure range.

<u>Figure 8</u> shows the recommended decoupling circuit for interfacing the output of the integrated sensor to the A/D input of a microprocessor or microcontroller. Proper decoupling of the power supply is recommended.





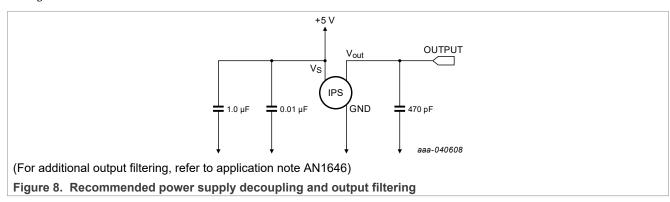
Nominal Transfer Value:

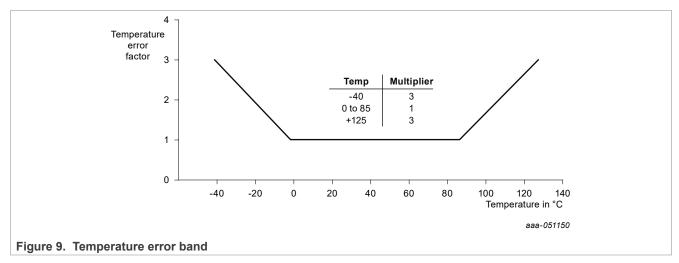
MPX5050

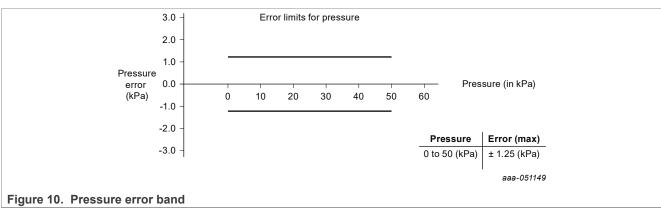
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$$V_{OUT} = V_S (P \times 0.018 + 0.04)$$

 $\pm (Pressure\ Error\ \times Temp.\ Factor\ \times 0.018\ V_S)$
 $V_S = 5.0\ V\ \pm 0.25\ Vdc$







6.2 Pressure (P1)/Vacuum (P2) side identification table

NXP Semiconductors designates the two sides of the pressure sensor as the Pressure (P1) side and the Vacuum (P2) side. The Pressure (P1) side is the side containing fluorosilicone gel which protects the die from harsh media. The MPX pressure sensor is designed to operate with positive differential pressure applied, P1 > P2.

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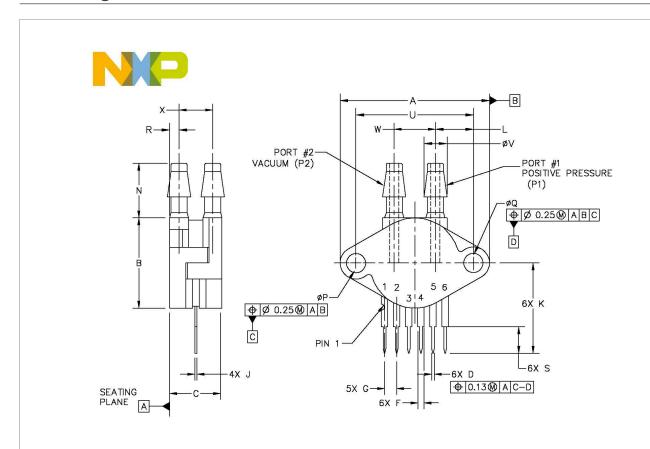
The Pressure (P1) side may be identified by using <u>Table 7</u>:

Table 7. Pressure (P1) side identification

Part Number	Case Type	Pressure (P1) Side Identifier
MPX5050DP	867C	Side with Part Marking
MPXV5050GP	1369	Side with Port Attached
MPXV5050DP	1351	Side with Part Marking
MPXV5050GC6/T1	482A	Vertical Port Attached

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7 Package outline



DIM	MILLIM MIN	IETERS MAX	DIM	MILLIM MIN	ETERS MAX	NOTES:		
Α	29.08	29.85	Р	ø3.89	ø4.04	1. DIMENSIONS ARE IN MILLIMETERS.		
В	17.40	18.16	Q	ø3.89	Ø4.04	2. DIMENSIONS AND TOLERANCES PER		
С	10.29	11.05	R	1.60	2.11	ASME Y14.5M-1994.		
D	0.68	0.84	S	5.59	6.10	3. 867C-01 THRU -04 OBSOLATE, NEW		
F	1.22	1.63	U	23.11	BSC	STANDARD 867C-05.		
G	2.54	BSC	V	4.62	4.93	3. STYLE 1:		
J	0.36	0.41	W	7.87	8.38	DW 4 W 0017		
K	17.65	18.42	X	6.30	7.06	PIN 1: V OUT 5: V2 2: GROUND 6: V EX		
L	7.37	7.62				3: VCC		
N	10.67	11.18				4: V1		
		NDUCTORS N.V. TS RESERVED		MECHA	NICAL OU	JTLINE PRINT VERSION NOT TO SCALE		
TITLE	DOCUMENT NO: 98ASB42797B REV: H							
	SENSOR, 4 LEAD UNIBODY					STANDARD: NON-JEDEC		
						SOT1756-1 29 JAN 2016		

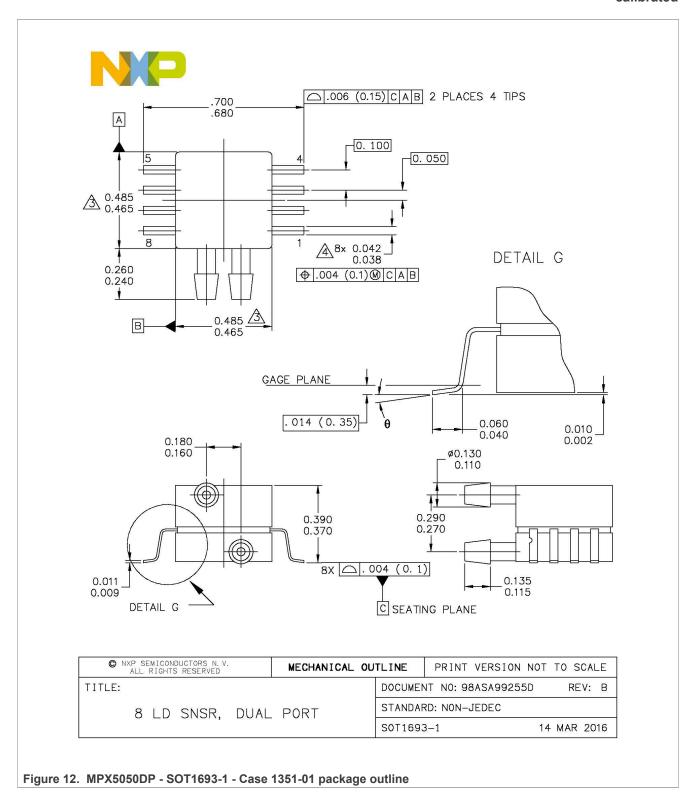
Figure 11. MPX5050DP - SOT17560-1 - Case 867C package outline ¹

MPX5050

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¹ Refer to Section 4.2 "Pin description", Table 3

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NOTES:

- 1. CONTROLLING DIMENSION: INCH
- 2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M-1994.

ADIMENSIONS DO NOT INCLUDE MOLD FLASH OR PPROTRUSIONS.
MOLD FLASH AND PROTRUSIONS SHALL NOT EXCEED .006 PER SIDE.

DIMENSION DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE .008 MAXIMUM.

STYLE 1:		STYLE 2:		
PIN 1:	GND	PIN	1:	N/C
PIN 2:	+Vou t	PIN	2:	Vs
PIN 3:	Vs	PIN	3:	GND
PIN 4:	–Vou t	PIN	4:	Vout
PIN 5:	N/C	PIN	5:	N/C
PIN 6:	N/C	PIN	6:	N/C
PIN 7:	N/C	PIN	7:	N/C
PIN 8:	N/C	PIN	8:	N/C

NXP SEMICONDUCTORS N. V. ALL RIGHTS RESERVED	MECHANICAL OUTLINE		PRINT VERSION NO	T TO SCALE
TITLE:		DOCUMEN	NT NO: 98ASA99255D	REV: B
8 LD SNSR, DUAL	PORT	STANDAF	RD: NON-JEDEC	
		S0T1693	3–1	14 MAR 2016

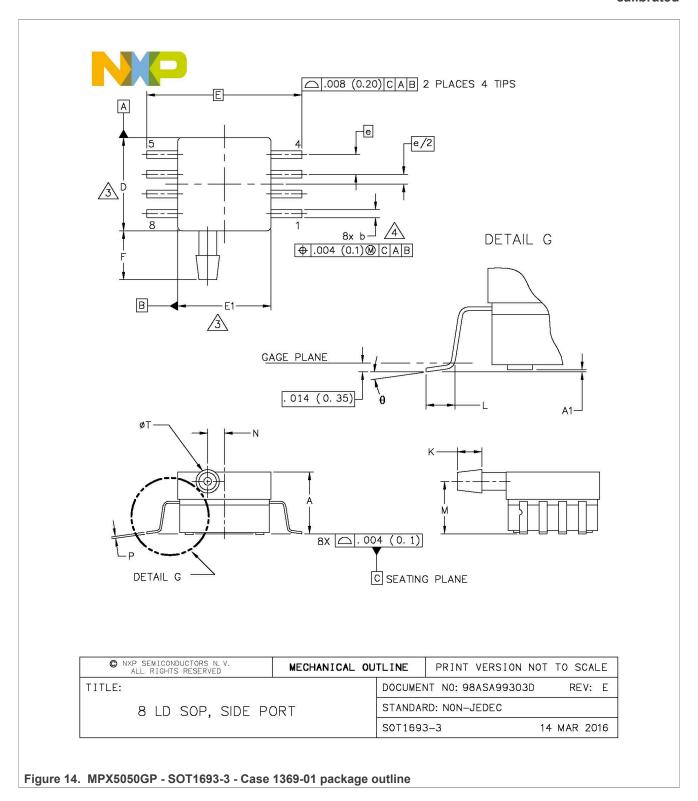
Figure 13. MPX5050DP - SOT1693-1 - Case 1351-01 package outline notes ²

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² Style 1 is not applicable for the parts covered by this data sheet.

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NOTES:

- 1. CONTROLLING DIMENSION: INCH
- 2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M-1994.
- △ DIMENSIONS DO NOT INCLUDE MOLD FLASH OR PPROTRUSIONS.

 MOLD FLASH AND PROTRUSIONS SHALL NOT EXCEED .006 (0.152) PER SIDE.
- A DIMENSION DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE .008 (0.203) MAXIMUM.

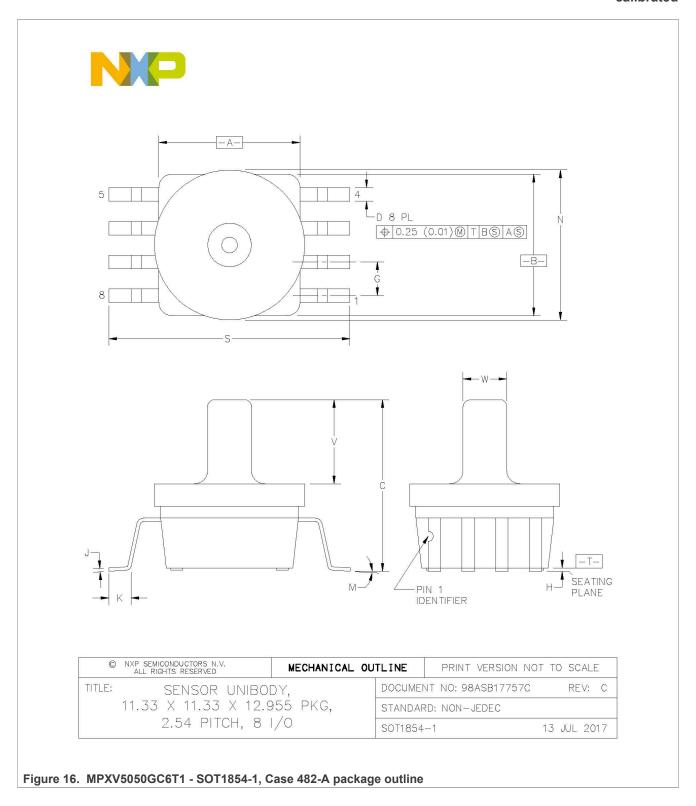
	INCHES MILLIMETERS			INCHES		MILLI	METERS		
DIM	MIN	MAX	MIN	MAX	DIM	MIN	MAX	MIN	MAX
Α	.300	.330	7.62	8.38	θ	0.	7.	0.	7.
A1	.002	.010	0.05	0.25	-			===	
b	.038	.042	0.96	1.07	-				
D	.465	.485	11.81	12.32	_				
E	.717	BSC	18	3.21 BSC	-				
E1	.465	.485	11.81	12.32	_				
е	.100	BSC	2.	54 BSC					<u></u>
F	.245	.255	6.22	6.47	_				
K	.120	.130	3.05	3.30	_				
L	.061	.071	1.55	1.80	_				
М	.270	.290	6.86	7.36	_				
N	.080	.090	2.03	2.28	_				
Р	.009	.011	0.23	0.28	_				
Ţ	.115	.125	2.92	3.17	_				
							ve en e perces si senior	AZMYA IZ SEEL BEEL MARKESA	20-000
	© NXP SEMICONDUCTORS N. V. ALL RIGHTS RESERVED MECHANICAL					TLINE	PRINT VER	SION NOT	TO SCALE
TIT	LE:					DOCUMEN	NT NO: 98ASA	99303D	REV: E
	8 LD SOP, SIDE PORT						RD: NON-JEDE	С	
*** ****** ******* * ******** * ** *****									

Figure 15. MPX5050GP - SOT1693-3 - Case 1369-01 package outline notes

S0T1693-3

14 MAR 2016

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NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M-1982.
- 2. CONTROLLING DIMENSION: INCH.
- 3. DIMENSION 'A' AND 'B' DO NOT INCLUDE MOLD PROTUSION.
- 4. MAXIMUM MOLD PROTRUSION 0.15 (0.006).
- 5. ALL VERTICAL SURFACES 5' TYPICAL DRAFT.

	INCH	HES	MILL	IMETERS				
DIM	MIN	MAX	MIN	MAX				
Α	0.415	0. 425	10. 54	10. 79				
В	0.415	0. 425	10. 54	10.79				
С	0.500	0. 520	12. 70	13. 21				
D	0. 038	0.042	0. 96	1.07				
G	0.100	BSC	2. 5	4 BSC				
Н	0. 002	0.010	0. 05	0.25				
J	0.009	0.011	0. 23	0. 28				
К	0.061	0.071	1. 55	1.80				
М	0°	7°	0°	7°				
N	0.444	0.448	11. 28	11.38				
S	0. 709	0.725	18. 01	18.41				
V	0. 245	0. 255	6. 22	6. 48				
W	0. 115	0. 125	2. 92	3. 17				
0	NXP SEMICONE ALL RIGHTS	DUCTORS N.V. RESERVED		MECHANICA	L OU	TLINE	PRINT VERSION NOT TO) SCALE
TITLE:	SE	INSOR L	JNIBOD,	Υ,		DOCUME	NT NO: 98ASB17757C	REV: C
	11.33 X			and the same of th		STANDAF	RD: NON-JEDEC	
	2.54 PITCH, 8 I/O S0T1854-1 13 JUL 2017							

Figure 17. MPXV5050GC6T1 - SOT1854-1, Case 482-A package outline notes

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8 Revision history

Table 8. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
MPX5050 v.12	20230609	Product data sheet	_	MPX5050 v.11
Modifications	guidelines of NXF name where appr Revised all image Section 3, remove MPVZ5050GW7U Section 3.1, inser Section 4, Section Section 5, rename Semiconductors of Section 6, rename Section 6.2, Table	ropriate. es to conform to NXP Se ed MPX505D, MPX5050 J from the table. ted new table. n 4.1, and Section 4.2, ir ed "Maximum ratings" se document heirarchy for o	texts have been ad miconductor image BP, MPX505GP1, MI nserted new sections ection to "Limiting valuta sheets. Stics" to "Recomme D and MPX5050GP1	apted to the new company guidelines. PXV5050GC6U and s. s. slues" to conform to NXP nded operating conditions".

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9 Legal information

9.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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Integrated silicon pressure sensor, on-chip signal conditioned, temperature compensated and calibrated

Tables

Tab. 1.	Ordering information1	Tab. 5.	Limiting values	3
Tab. 2.	Ordering options2	Tab. 6.	Recommended operating conditions	4
Tab. 3.	Pin descriptions - MPX5050DP3	Tab. 7.	Pressure (P1) side identification	
Tab. 4.	Pin descriptions - MPXV5050GC6T1,	Tab. 8.	Revision history	
	MPXV5050DP, and MPXV5050GP 3		,	
Figur	res			
	MDV5050DD 00T47504 0 007005	F: 40	NDV5555DD COTTOOL C 105101	
Fig. 1.	MPX5050DP - SOT1756-1 - Case 867C-052	Fig. 12.	MPX5050DP - SOT1693-1 - Case 1351-01	_
Fig. 2.	MPXV5050DP Case 1351-012		package outline	9
Fig. 3.	MPXV5050GP Case 1369-01 2	Fig. 13.	MPX5050DP - SOT1693-1 - Case 1351-01	
Fig. 4.	MPXV5050GC6T1 – Case 482A-012		package outline notes	10
Fig. 5.	Fully Integrated Pressure Sensor	Fig. 14.	MPX5050GP - SOT1693-3 - Case 1369-01	
	Schematic4		package outline	11
Fig. 6.	Output vs. pressure differential5	Fig. 15.	MPX5050GP - SOT1693-3 - Case 1369-01	
Fig. 7.	Cross-sectional diagram (not to scale)5	· ·	package outline notes	12
Fig. 8.	Recommended power supply decoupling	Fig. 16.	MPXV5050GC6T1 - SOT1854-1, Case	
5	and output filtering6	3	482-A package outline	13
Fig. 9.	Temperature error band6	Fig. 17.		
Fig. 10.	Pressure error band6	J	482-A package outline notes	14
Fig. 11.	MPX5050DP - SOT17560-1 - Case 867C			
	package outline8			
	pasitage satisfic			

Integrated silicon pressure sensor, on-chip signal conditioned, temperature compensated and

Contents

1	General description	1
2	Feature and benefits	1
3	Ordering information	1
3.1	Ordering options	
4	Pinning information	2
4.1	Pinning	
4.2	Pin description	3
5	Limiting values	3
6	Recommended operating conditions	4
6.1	On-chip Temperature Compensation and Calibration	5
6.2	Pressure (P1)/Vacuum (P2) side identification table	
7	Package outline	
8	Revision history	
9	l egal information	

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